

Early and favorable consideration with respect to this application is respectfully requested.

Should any questions arise in connection with this application, the undersigned respectfully requests that he be contacted at the number indicated below.

BURNS, DOANE, SWECKER & MATHIS, L.L.P.

Platon N. Mandros
Registration No. 22,124

Date: December 6, 2001

Attachment to Preliminary Amendment dated December 6, 2001

Marked-up Claims

13. (Amended) A semiconductor device accordin to claim 1 [or claim 4],
comprising a SRAM cell, wherein the wiring layer is connected to the memory node of the
SRAM cell.

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